# **OSRAM** BPX 80 **Datasheet**

Discontinued





## **Array Linear**

## **BPX 80**

Silicon NPN Phototransistor Arrays





## **Applications**

- Factory Automation

#### **Features**

- Package: clear epoxy
- ESD: 2 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)
- Spectral range of sensitivity: (typ) 450 ... 1100 nm
- Multiple-digit array package
- High linearity
- Available in groups



## **Ordering Information**

Type	Photocurrent 1)	Photocurrent 2)	Ordering Code
		typ.	
	$V_{CE} = 5 \text{ V}; \lambda = 950 \text{ nm}; E$	$_{\rm e}$ = 0.5 mW/cm $^{2}$ V $_{\rm CE}$ = 5 V; $\lambda$ = 950 nm; E $_{\rm e}$ = 0.	.5 mW/cm²
	I <sub>PCE</sub>	I <sub>PCE</sub>	
BPX 80	360 900 μA	660 μΑ	Q62702P0028

Only one bin within one packing unit (variation less than 2:1)



## **Maximum Ratings**

T<sub>A</sub> = 25 °C

Parameter	Symbol		Values
Operating temperature	T <sub>op</sub>	min.	-40 °C
	οp	max.	80 °C
Storage temperature	T <sub>stg</sub>	min.	-40 °C
	Sig	max.	80 °C
Collector-emitter voltage	V <sub>CE</sub>	max.	35 V
Collector current	I <sub>c</sub>	max.	50 mA
Collector surge current	I <sub>cs</sub>	max.	200 mA
τ ≤ 10 μs			
Emitter-collector voltage	$V_{EC}$	max.	7 V
Total power dissipation	P <sub>tot</sub>	max.	90 mW
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM, Class 2)	$V_{ESD}$	max.	2 kV

#### **Characteristics**

T<sub>A</sub> = 25 °C

Parameter	Symbol		Values
Number of detectors	n		10
Dimension "B" (see drawing)	I	max. min.	25.2 mm 24.8 mm
Wavelength of max sensitivity	$\lambda_{_{ ext{S max}}}$	typ.	850 nm
Spectral range of sensitivity	λ <sub>10%</sub>	typ.	450 1100 nm
Dimensions of chip area	L×W	typ.	0.55 x 0.55 mm x mm
Radiant sensitive area	А	typ.	0.11 mm²
Half angle	φ	typ.	18 °
Photocurrent $V_{CE} = 5 \text{ V}$ ; Std. Light A; $E_v = 1000 \text{ lx}$	I <sub>PCE</sub>	typ.	1900 μΑ
Dark current V <sub>CE</sub> = 5 V	I <sub>CE0</sub>	typ. max.	1 nA 50 nA
Rise time $I_C = 1 \text{ mA}$ ; $\lambda = 0 \text{ nm}$ ; $V_{CE} = 5 \text{ V}$ ; $R_L = 1 \text{ k}\Omega$	t <sub>r</sub>	typ.	6 µs
Fall time $I_C = 1 \text{ mA}$ ; $\lambda = 0 \text{ nm}$ ; $V_{CE} = 5 \text{ V}$ ; $R_L = 1 \text{ k}\Omega$	t <sub>f</sub>	typ.	6 µs
Collector-emitter saturation voltage $^{3)}$ $I_{\rm C} = I_{\rm PCE,min} \times 0.3$ ; $\lambda = 950 \text{ nm}$ ; $E_{\rm e} = 0.5 \text{ mW/cm}^2$ ; $0$	$V_{CEsat}$	typ.	150 mV
Capacitance $V_{CE} = 0 \text{ V}$ ; $f = 1 \text{ MHz}$ ; $E = 0$	C <sub>CE</sub>	typ.	7.5 pF

## **Photocurrent Groups**

 $T_A = 25$  °C

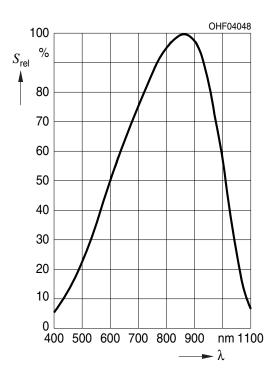
Group	Photocurrent <sup>1)</sup> $V_{CE} = 5 \text{ V}; \lambda = 950 \text{ nm}; E_{e} = 0.5 \text{ mW/cm}^{2} \text{ min.}$ $I_{PCE}$	Photocurrent <sup>1)</sup> $V_{CE} = 5 \text{ V}; \lambda = 950 \text{ nm}; E_{e} = 0.5 \text{ mW/cm}^{2} \text{ max.}$ $I_{PCE}$
A	360 μΑ	560 μA
В	450 μΑ	710 µA
С	560 μΑ	900 μΑ

For delivery the components are marked -A, -B, -C. Due to differing yields it is not possible to order a definite group.



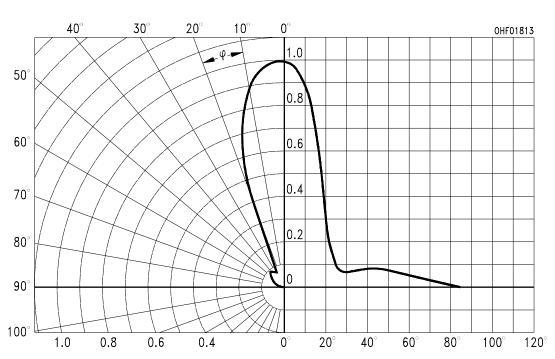
## Relative Spectral Sensitivity 4), 5)

 $S_{rel} = f(\lambda)$ 



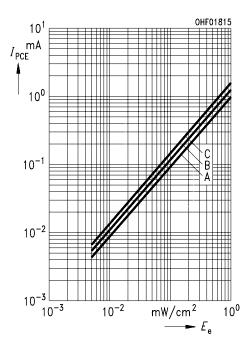
### Directional Characteristics 4), 5)

 $S_{rel} = f(\phi)$ 



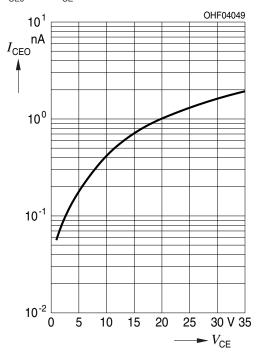
#### Photocurrent 4), 5)

$$I_{PCE} = f(E_e)$$
;  $V_{CE} = 5 V$ 



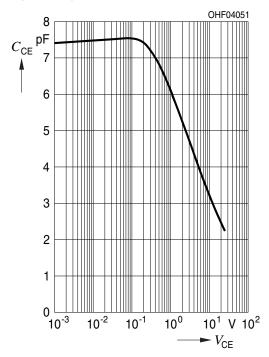
#### Dark Current 4), 5)

$$I_{CE0} = f(V_{CE}); E = 0$$



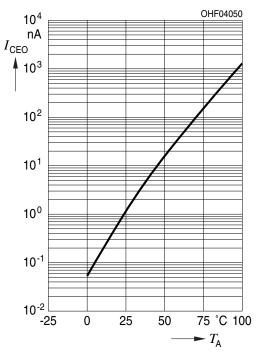
## Collector-Emitter Capacitance 4), 5)

$$C_{CE} = f(V_{CE}); f = 1 \text{ MHz}; E = 0$$



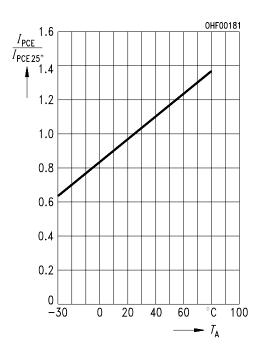
#### Dark Current 4)

$$I_{_{\mathrm{CE0}}}$$
 = f ( $T_{_{\mathrm{A}}}$ );  $V_{_{\mathrm{CE}}}$  = 0 V; E = 0 ;  $E_{_{\mathrm{e}}}$  = 0 mW/cm²; 0



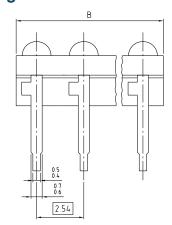
#### Photocurrent 4)

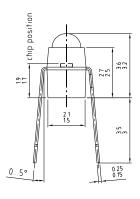
$$I_{PCE,rel} = f(T_A); V_{CE} = 5 V; Std. Light A$$

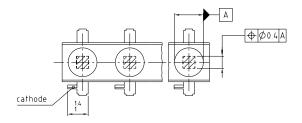




## Dimensional Drawing 6)







C63062-A370-A12..-07

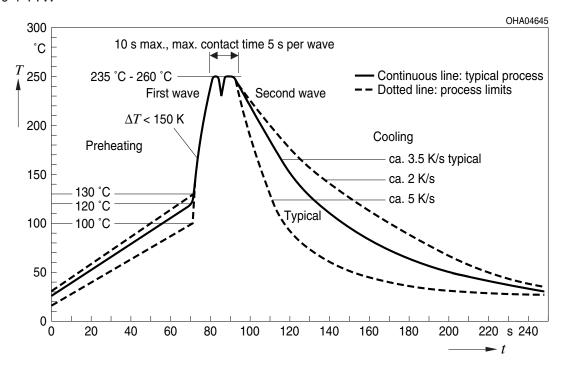
#### **Further Information:**

**Approximate Weight:** 240.0 mg

Package marking: Cathode

#### **TTW Soldering**

IEC-61760-1 TTW



#### Disclaimer

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

#### **Packing**

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

#### Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and /or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.

#### Glossary

- Photocurrent: The photocurrent values are measured (by irradiating the devices with a homogenous light source and applying a voltage to the device) with a tolerance of ±11 %.
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- 3) IPCEmin: IPCEmin is the min. photocurrent of the specified group.
- Typical Values: Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- <sup>5)</sup> **Testing temperature:** TA = 25°C (unless otherwise specified)
- Tolerance of Measure: Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.



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Version	Date	Change
1.4	2023-06-06	New Layout
		Applications
		Discontinued

#### Discontinued



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